

1417-6A

6 Watts, 28 Volts, Class C Microwave 1400 - 1700 MHz

GENERAL DESCRIPTION

The 1417-6A is an internally matched, COMMON BASE transistor capable of providing 6 watts of CW RF Output power across the 1400-1700 MHz band. This transistor is specifically designed for telemetry and telecommunications applications. It utilizes gold metalization and diffused ballasting to provide high reliability and superior ruggedness.

ABSOLUTE MAXIMUM RATINGS

Maximum Power Dissipation @ 25°C 19 Watts

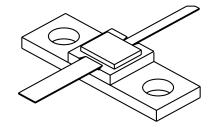
Maximum Voltage and Current

BVces Collector to Emitter Voltage 50 Volts
BVebo Emitter to Base Voltage 3.5 Volts
Ic Collector Current 1.0 Amps

Maximum Temperatures

Storage Temperature $- 65 \text{ to} + 200^{\circ}\text{C}$ Operating Junction Temperature $+ 200^{\circ}\text{C}$

CASE OUTLINE 55LV, STYLE 1



ELECTRICAL CHARACTERISTICS @ 25 °C

SYMBOL	CHARACTERISTICS	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Pout Pin Pg ηc VSWR1	Power Output Power Input Power Gain Collector Efficiency Load Mismatch Tolerance	F = 1.4 - 1.7 GHz Vcc = 28 Volts	6.0 7.2	7.5 40	1.14	Watt dB %

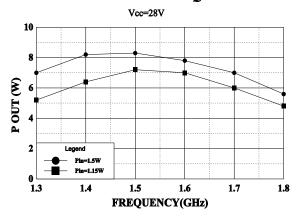
BVebo BVces	Emitter to Base Breakdown Collector to Emitter Breakdown	Ie = 3.0 mA Ic = 25mA	3.5 55			Volts Volts
Icbo Cob	Collector Leakage Current Output Capacitance	Vcb = 28 V Vcb = 28 V, F=1 MHz	33	1.0 6.5		mA pF
Hfe θjc	DC - Current Gain Thermal Resistance	Ic = 100 mA, Vce = 5V TC = 25°C	20	0.5	100 9.0	°C/W

Initial Issue June, 1994

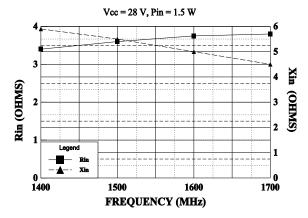
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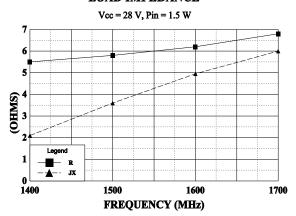
POWER OUTPUT VS FREQUENCY



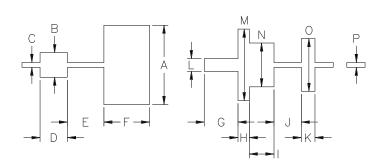
INPUT IMPEDANCE



LOAD IMPEDANCE

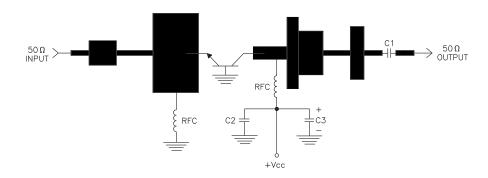


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REVISIONS				
ZONE	REV	DESCRIPTION	DATE	APPROVED



DIM	INCHES
Α	.870
В	.270
С	.053
D	.300
Е	.400
F	.500
G	.370
Н	.125
I	.270
J	.300
K	.150
L	.140
М	.785
N	.480
0	.580
Р	.053

1417-6A TEST CIRCUIT



DIELECTRIC = 19.4 MIL THICK TFE, Er=2.43 C1, C2 = 62pF CHIP ATC "A" C3 = 10MFD @ 35V RFC = 4 turns #22 wire 1/16" I.D.



cage 0PJR2	DWG NO.	1417-6A		REV A
	SCALE	1/1	SHEET	